

TPS6305x 开关电流为 1A、具备可调节软启动功能的单电感降压-升压转换器

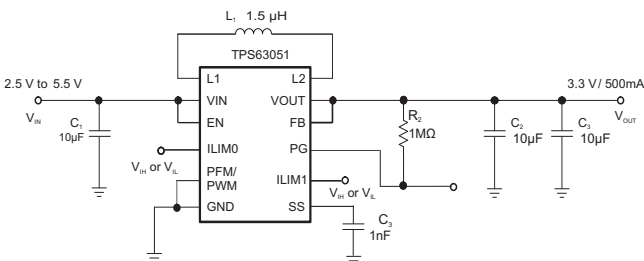
1 特性

- 实时降压或升压，支持在降压和升压模式之间无缝转换
- 输入电压范围为 2.5V 至 5.5V
- 0.5A 持续输出电流： $V_{IN} \geq 2.5V$ 、 $V_{OUT} = 3.3V$
- 具有可调节输出电压和固定输出电压两个版本可选
- 在升压模式中效率大于 90%，在降压模式中效率大于 95%
- 开关频率典型值为 2.5MHz
- 平均输入电流限制可调节
- 软启动时间可调节
- 器件静态电流小于 60 μ A
- 具有自动节电模式或强制 PWM 模式
- 关断期间负载断开
- 提供过热保护
- 采用 1.6mm x 1.2mm、12 引脚 WCSP 小型封装和 2.5mm x 2.5mm、12 引脚、HotRod™ QFN 封装
- 借助以下工具创建定制设计方案：
 - TPS63050，使用 [WEBENCH® 电源设计器](#)
 - TPS63051，使用 [WEBENCH® 电源设计器](#)

2 应用

- 手机和智能电话
- 平板电脑
- PC 和智能手机附件
- 通过电池供电的应用
- 智能电网/智能仪表

简化原理图 (WCSP)



3 说明

TPS6305x 系列器件是一款静态电流较低的高效降压/升压转换器，适用于输入电压高于或低于输出电压的应用。

在升压模式下，持续输出电流最高可达 500mA；在降压模式下，持续输出最高可达 1A。最大平均开关电流限制为 1A（典型值）。TPS6305x 系列器件在整个输入电压范围内针对输出电压进行稳压操作，可根据输入电压自动切换为降压或升压模式，从而在两种模式之间实现无缝转换。

该降压/升压转换器基于使用同步整流的固定频率 PWM 控制器，可实现最高效率。在负载电流较低的情况下，该转换器进入节能模式，从而在整个负载电流范围内保持高效率。

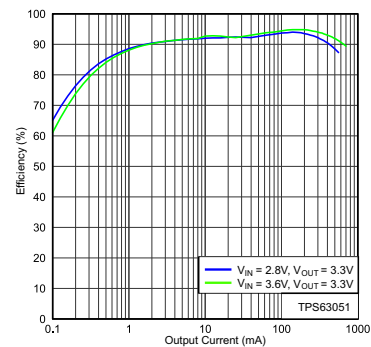
用户可以通过脉频调制 (PFM)/PWM 引脚选择自动 PFM/PWM 工作模式或强制 PWM 工作模式。在 PWM 模式下通常使用 2.5MHz 固定频率。使用一个外部电阻分压器可对输出电压进行编程，或者在芯片上对输出电压进行内部固定。转换器可被禁用以最大限度地减少电池消耗。在关断期间，负载从电池上断开。该器件采用 12 引脚芯片尺寸球状引脚栅格阵列 (DSBGA) 封装和 12 引脚 HotRod 封装。

器件信息(1)

器件型号	封装	封装尺寸（标称值）
TPS63050	DSBGA (12)	1.56mm x 1.16mm
TPS63051	VQFN (12)	2.50mm x 2.50mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

效率与输出电流间的关系



目录

1	特性	1	9	Application and Implementation	15
2	应用	1	9.1	Application Information	15
3	说明	1	9.2	Typical Application	15
4	修订历史记录	2	10	Power Supply Recommendations	23
5	Device Comparison Table	4	11	Layout	23
6	Pin Configuration and Functions	4	11.1	Layout Guidelines	23
7	Specifications	5	11.2	Layout Example (WCSP)	23
7.1	Absolute Maximum Ratings	5	11.3	Layout Example (HotRod)	23
7.2	ESD Ratings	5	11.4	Thermal Considerations	24
7.3	Recommended Operating Conditions	5	12	器件和文档支持	24
7.4	Thermal Information	5	12.1	使用 WEBENCH® 工具创建定制设计	24
7.5	Electrical Characteristics	6	12.2	器件支持	24
7.6	Switching Characteristics	7	12.3	相关链接	24
7.7	Typical Characteristics	8	12.4	接收文档更新通知	25
8	Detailed Description	9	12.5	社区资源	25
8.1	Overview	9	12.6	商标	25
8.2	Functional Block Diagrams	9	12.7	静电放电警告	25
8.3	Feature Description	11	12.8	Glossary	25
8.4	Device Functional Modes	12	13	机械、封装和可订购信息	25

4 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

Changes from Revision C (July 2015) to Revision D	Page
• 在数据表中添加了 Webench 链接	1
• Changed the Pin Configurations	4
• Changed the quiescent current V_{IN} max value From: 60 μA To: 65 μA in the <i>Electrical Characteristics</i>	6
• Added Note: Conditions: $T_J = -40^{\circ}C$ to $85^{\circ}C$ To the quiescent current and shutdown current in the <i>Electrical Characteristics</i>	6

Changes from Revision B (April 2015) to Revision C	Page
• 已添加 新封装选项至 项目符号	1
• 已添加 VQFN 封装至器件信息表	1
• Added HotRod Pin Configuration and Functions	4
• Added Parameter Measurement Circuit for HotRod package option	15

Changes from Revision A (February 2014) to Revision B	Page
• 已更改 说明 部分的第四段	1
• 已更改 图形图像	1
• Changed Ordering Information table To: Device Comparison Table	4
• Changed "Handling Ratings" table to "ESD Rating" table and moved T_{stg} spec to the Absolute Maximum Ratings table	5
• Moved some Typical Characteristics graphs to the Application Curves section	8

Changes from Original (July 2013) to Revision A
Page

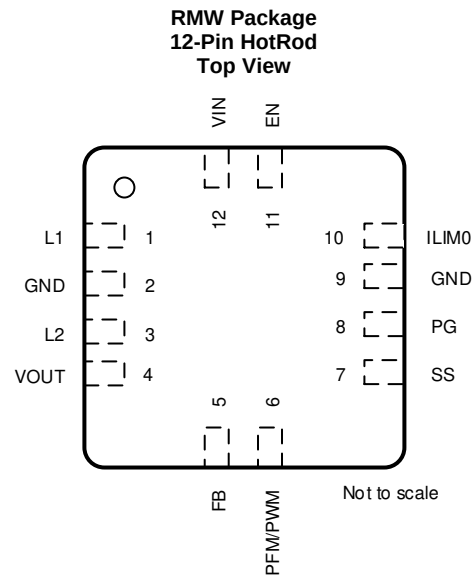
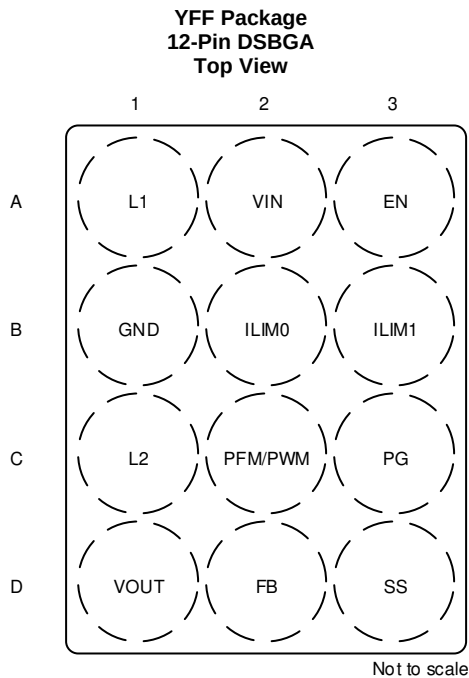
• 已添加 器件信息表, ESD 额定值表, 特性 描述部分, 器件功能模式, 应用和实施部分, 电源相关建议部分, 布局部分, 器件和文档支持部分以及机械、封装和可订购信息部分	1
• 已添加 TPS63050 器件规范和 说明 至整篇数据手册	1
• Changed Figure 34 , PCB Layout	23
• Changed Figure 35 , PCB Layout	23

5 Device Comparison Table

PART NUMBER ⁽¹⁾	V _{OUT}
TPS63050	Adjustable
TPS63051	3.3 V

(1) For all available packages, see the orderable addendum at the end of the datasheet

6 Pin Configuration and Functions



Pin Functions

PIN			I/O	DESCRIPTION
NAME	WCSP	HotRod		
EN	A3	11	I	Enable input. (1 enabled, 0 disabled). It must not be left floating
FB	D2	5	I	Voltage feedback of adjustable versions, must be connected to VOUT on fixed output voltage versions1
GND	B1	2,9		Ground for Power stage and Control stage
ILIM0	B2	10	I	Programmable inrush current limit input works together with I _{LIM1} . See table on page 1. It must not be left floating
ILIM1	B3	See ⁽¹⁾	I	Programmable inrush current limit input works together with I _{LIM0} . See 效率与输出电流间的关系 on page 1. Do not leave floating
L1	A1	1		Connection for Inductor
L2	C1	3		Connection for Inductor
PFM/PWM	C2	6	I	0 for PFM mode 1 for forced PWM mode. It must not be left floating
PG	C3	8	O	Power good open drain output
SS	D3	7	I	Adjustable Soft-Start. If left floating default soft-start time is set
VIN	A2	12	I	Supply voltage for power stage and control stage
VOUT	D1	4	O	Buck-boost converter output

(1) Only available with DSBGA package, for VQFN package ILIM1 is internally connected to voltage level > V_{IH}

7 Specifications

7.1 Absolute Maximum Ratings

over junction temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Voltage ⁽²⁾	V _{IN} , L1, EN, V _{OUT} , FB, V _{IN} A, PFM/PWM	−0.3	7	V
	L2 ⁽³⁾	−0.3	7	
	L2 ⁽⁴⁾	−0.3	9.5	
Operating junction temperature, T _J		−40	150	°C
Operating ambient temperature, T _A		−40	85	°C
Storage temperature, T _{stg}		−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground pin.
- (3) DC voltage rating.
- (4) AC voltage rating.

7.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±1500	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±700	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

See ⁽¹⁾		MIN	NOM	MAX	UNIT
V _{IN}	Input voltage	2.5		5.5	V
I _{OUT}	Output current			0.5	A
L	Inductance ⁽²⁾	1	1.5	2.2	μH
C _{OUT}	Output capacitance ⁽³⁾	10			μF
T _A	Operating ambient temperature	−40		85	°C
T _J	Operating virtual junction temperature	−40		125	°C

- (1) Refer to the Application Information section for further information
- (2) Effective inductance value at operating condition. The nominal value given matches a typical inductor to be chosen to meet the inductance required.
- (3) Due to the DC bias effect of ceramic capacitors, the effective capacitance is lower than the nominal value when a voltage is applied. This is why the capacitance is specified to allow the selection of the nominal capacitor required with the DC bias effect for this type of capacitor. The nominal value given matches a typical capacitor to be chosen to meet the minimum capacitance required.

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS6305x		UNIT
		WCSP	RMW	
		12 PINS	12 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	89.9	37.3	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	0.7	30.4	°C/W
R _{θJB}	Junction-to-board thermal resistance	43.9	8.0	°C/W
ψ _{JT}	Junction-to-top characterization parameter	2.9	0.4	°C/W
ψ _{JB}	Junction-to-board characterization parameter	43.7	7.8	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	n/a	2.5	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.5 Electrical Characteristics

 $V_{IN} = 3.6\text{ V}$, $T_J = -40^\circ\text{C}$ to 125°C , typical values are at $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
V_{IN}	Input voltage range		2.5		5.5	V
V_{IN_Min}	Minimum input voltage to turn on in full load	$I_{OUT} = 500\text{ mA}$		2.7		V
I_{OUT}	Output current ⁽¹⁾	$I_{LIM0} = V_{IH}$, $I_{LIM1} = V_{IH}$		500		mA
I_Q	Quiescent current ⁽²⁾	V_{IN} $I_{OUT} = 0\text{ mA}$, $EN = V_{IN} = 3.6\text{ V}$, $V_{OUT} = 3.3\text{ V}$		43	65	μA
		V_{OUT} $I_{OUT} = 0\text{ mA}$, $EN = V_{IN} = 3.6\text{ V}$, $V_{OUT} = 3.3\text{ V}$			10	
I_{sd}	Shutdown current ⁽²⁾	$EN = 0\text{ V}$		0.1	1	μA
$UVLO_{TH}$	Undervoltage lockout threshold	V_{IN} falling	1.6	1.7	1.8	V
$UVLO_{hys}$	Undervoltage lockout hysteresis			200		mV
T_{SD}	Thermal shutdown	Temperature rising		140		$^\circ\text{C}$
$T_{SD(hys)}$	Thermal shutdown hysteresis			20		$^\circ\text{C}$
LOGIC SIGNALS EN, I_{LIM0}, I_{LIM1}						
V_{IH}	High level input voltage	$V_{IN} = 2.5\text{ V to } 5.5\text{ V}$	1.2			V
V_{IL}	Low level voltage Input Voltage	$V_{IN} = 2.5\text{ V to } 5.5\text{ V}$			0.3	V
I_{ikg}	Input leakage current	PFM / PWM, EN , I_{LIM0} , $I_{LIM1} = \text{GND or } V_{IN}$		0.01	0.1	μA
POWER GOOD						
V_{OL}	Low level voltage	$I_{sink} = 100\text{ }\mu\text{A}$			0.3	V
I_{PG}	PG sinking current	$V = 0.3\text{ V}$			0.1	mA
I_{ikg}	Input leakage current	$V_{PG} = 3.6\text{ V}$		0.01	0.1	μA
OUTPUT						
V_{OUT}	Output voltage range		2.5		5.5	V
V_{FB}	TPS63050 feedback regulation voltage			0.8		V
V_{FB}	TPS63050 feedback voltage accuracy	PWM mode	-1.1%		1.1%	
V_{FB}	TPS63050 feedback voltage accuracy ⁽³⁾	PFM mode	-1%		3%	
V_{OUT}	TPS63051 output voltage accuracy	PWM mode	3.27	3.3	3.34	V
V_{OUT}	TPS63051 output voltage accuracy ⁽³⁾	PFM mode	3.27	3.3	3.39	V
$I_{PWM \rightarrow PFM}$	Minimum output current to enter PFM mode	$V_{IN} = 3\text{ V}$; $V_{OUT} = 3.3\text{ V}$		150		mA
I_{FB}	TPS63050 feedback input bias current	$V_{FB} = 0.8\text{ V}$		10	100	nA
$R_{DS(on)}$	Input high-side FET on-resistance	$I_{SW} = 500\text{ mA}$		145		m Ω
	Output high-side FET on-resistance	$I_{SW} = 500\text{ mA}$		95		m Ω
	Input low-side FET on-resistance	$I_{SW} = 500\text{ mA}$		170		m Ω
	Output low-side FET on-resistance	$I_{SW} = 500\text{ mA}$		115		m Ω
I_{IN_MAX}	Input current-limit boost mode	$I_{LIM0} = V_{IH}$, $I_{LIM1} = V_{IH}$, $V_{IN} = 2.7\text{ V to } 3\text{ V}$, $V_{OUT} = 3\text{ V}$	480		1240	mA
		$I_{LIM0} = V_{IH}$, $I_{LIM1} = V_{IH}$, $V_{IN} = 2.7\text{ V to } 3.3\text{ V}$, $V_{OUT} = 3.3\text{ V}$	550		1400	mA
		$I_{LIM0} = V_{IH}$, $I_{LIM1} = V_{IH}$, $V_{IN} = 2.7\text{ V to } 4.5\text{ V}$, $V_{OUT} = 4.5\text{ V}$	630		1950	mA

(1) For minimum and maximum output current in a specific working point see [Figure 1](#) and [Figure 2](#); and [Equation 1](#) through [Equation 4](#).

(2) Conditions: $T_J = -40^\circ\text{C}$ to 85°C

(3) Conditions: $f = 2.5\text{ MHz}$, $L = 1.5\text{ }\mu\text{H}$, $C_{OUT} = 10\text{ }\mu\text{F}$

Electrical Characteristics (continued)

 $V_{IN} = 3.6\text{ V}$, $T_J = -40^{\circ}\text{C}$ to 125°C , typical values are at $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{SS_IN}	Programmable inrush current limit ⁽⁴⁾	$I_{LIM0} = V_{IL}$, $I_{LIM1} = V_{IL}$, $V_{IN} = 3\text{ V}$, $V_{OUT} = 3.3\text{ V}$, (Available for DBGA only)		$0.4 \times I_{IN_MAX}$		mA
		$I_{LIM0} = V_{IH}$, $I_{LIM1} = V_{IL}$, $V_{IN} = 3\text{ V}$, $V_{OUT} = 3.3\text{ V}$, (Available for DBGA only)		$0.5 \times I_{IN_MAX}$		
		$I_{LIM0} = V_{IL}$, $I_{LIM1} = V_{IH}$, $V_{IN} = 3\text{ V}$, $V_{OUT} = 3.3\text{ V}$		$0.65 \times I_{IN_MAX}$		
		$I_{LIM0} = V_{IH}$, $I_{LIM1} = V_{IH}$, $V_{IN} = 3\text{ V}$, $V_{OUT} = 3.3\text{ V}$		I_{IN_MAX}		
I_{SS}	Soft-start current TPS63051			1		μA
I_{SS}	Soft-start current TPS63050			3.2		μA
	Line regulation	$V_{IN} = 2.5\text{ V}$ to 5.5 V , $I_{OUT} = 500\text{ mA}$, PWM mode		0.963		mV/V
	Load regulation	$V_{IN} = 3.6\text{ V}$, $I_{OUT} = 0\text{ mA}$ to 500 mA , PWM mode		4		mV/A

(4) For variation of this parameter with Input voltage see [Figure 3](#).

7.6 Switching Characteristics

 $V_{IN} = 3.6\text{ V}$, $T_J = -40^{\circ}\text{C}$ to 125°C , typical values are at $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OUTPUT						
f_s	Switching frequency			2.5		MHz
t_{SS}	Softstart time	$V_{OUT} = EN = \text{low to high}$, SS = floating, Buck mode $V_{IN} = 3.6\text{ V}$, $V_{OUT} = 3.3\text{ V}$, $I_{OUT} = 500\text{ mA}$ ⁽¹⁾		280		μs
		$V_{OUT} = EN = \text{low to high}$, SS = floating, Boost mode $V_{IN} = 2.5\text{ V}$, $V_{OUT} = 3.3\text{ V}$, $I_{OUT} = 500\text{ mA}$ ⁽¹⁾		600		
t_d	Start up delay	Time from when EN = high to when device starts switching		100		μs

(1) For variation of this parameter with Input voltage see [Figure 3](#).

7.7 Typical Characteristics

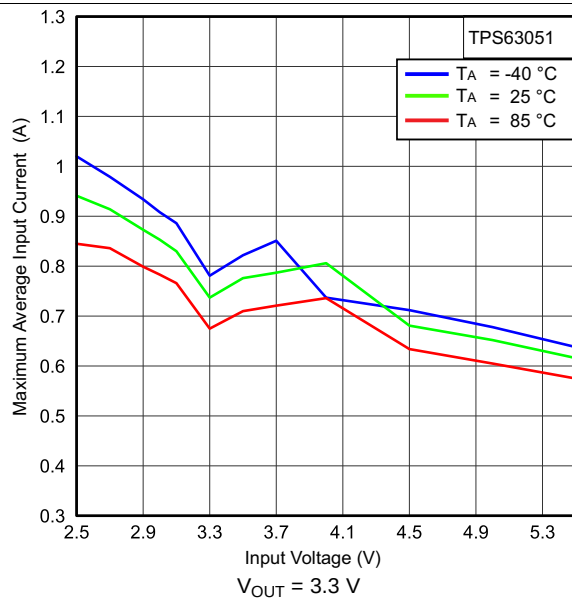


Figure 1. Maximum Average Input Current vs Input Voltage

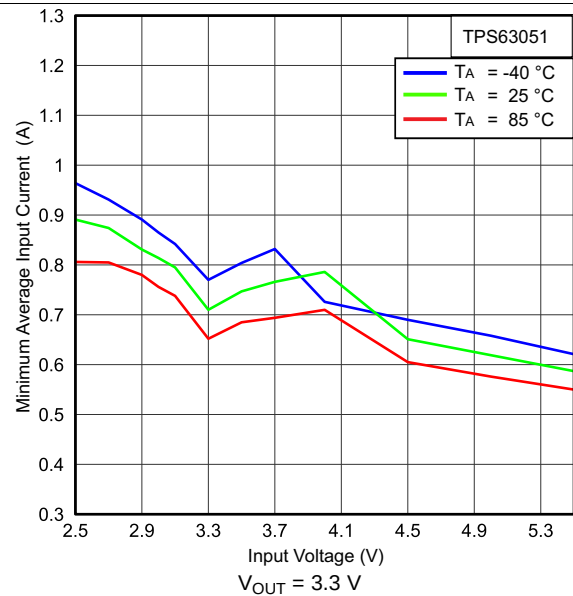


Figure 2. Minimum Average Input Current vs Input Voltage

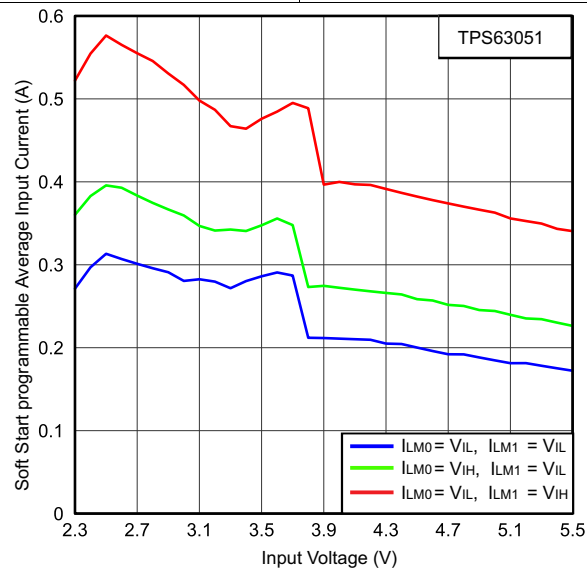


Figure 3. Programmable Average Input Current vs Input Voltage⁽¹⁾

(1) All options only available with the DSBGA package. For VQFN package ILM1 is internally connected to voltage level $> V_{IH}$

8 Detailed Description

8.1 Overview

The TPS6305x devices use 4 internal N-channel MOSFETs to maintain synchronous power conversion at all possible operating conditions. This enables the device to keep high efficiency over the complete input voltage and output power range. To regulate the output voltage at all possible input voltage conditions, the device automatically switches from buck operation to boost operation and back as required by the configuration. It always uses one active switch, one rectifying switch, one switch held on, and one switch held off. Therefore, it operates as a buck converter when the input voltage is higher than the output voltage, and as a boost converter when the input voltage is lower than the output voltage. There is no mode of operation in which all 4 switches are switching at the same time. Keeping one switch on and one switch off eliminates their switching losses. The RMS current through the switches and the inductor is kept at a minimum, to minimize switching and conduction losses. Controlling the switches this way allows the converter to always keep higher efficiency.

The device provides a seamless transition from buck to boost or from boost to buck operation.

8.2 Functional Block Diagrams

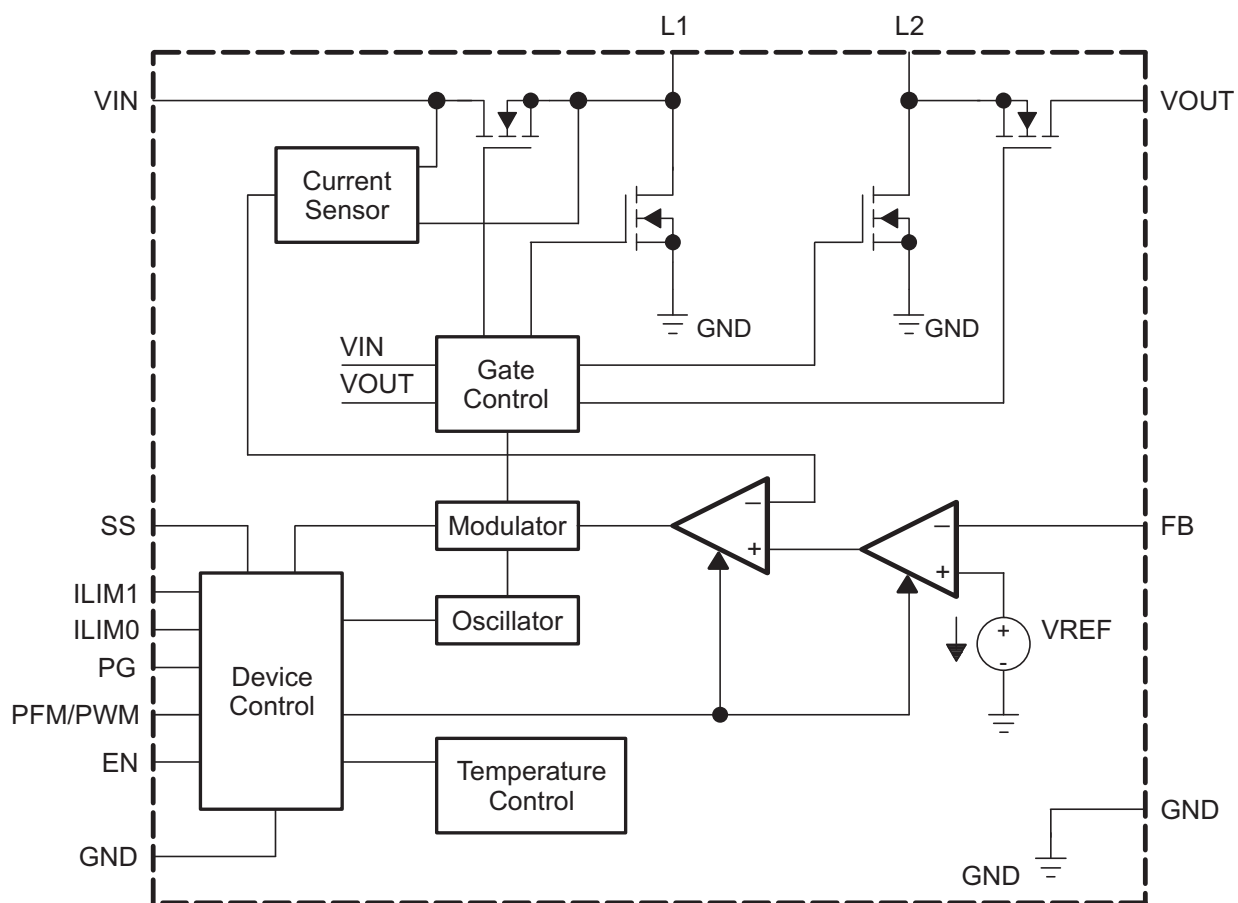


Figure 4. TPS63050 Block Diagram

Functional Block Diagrams (continued)

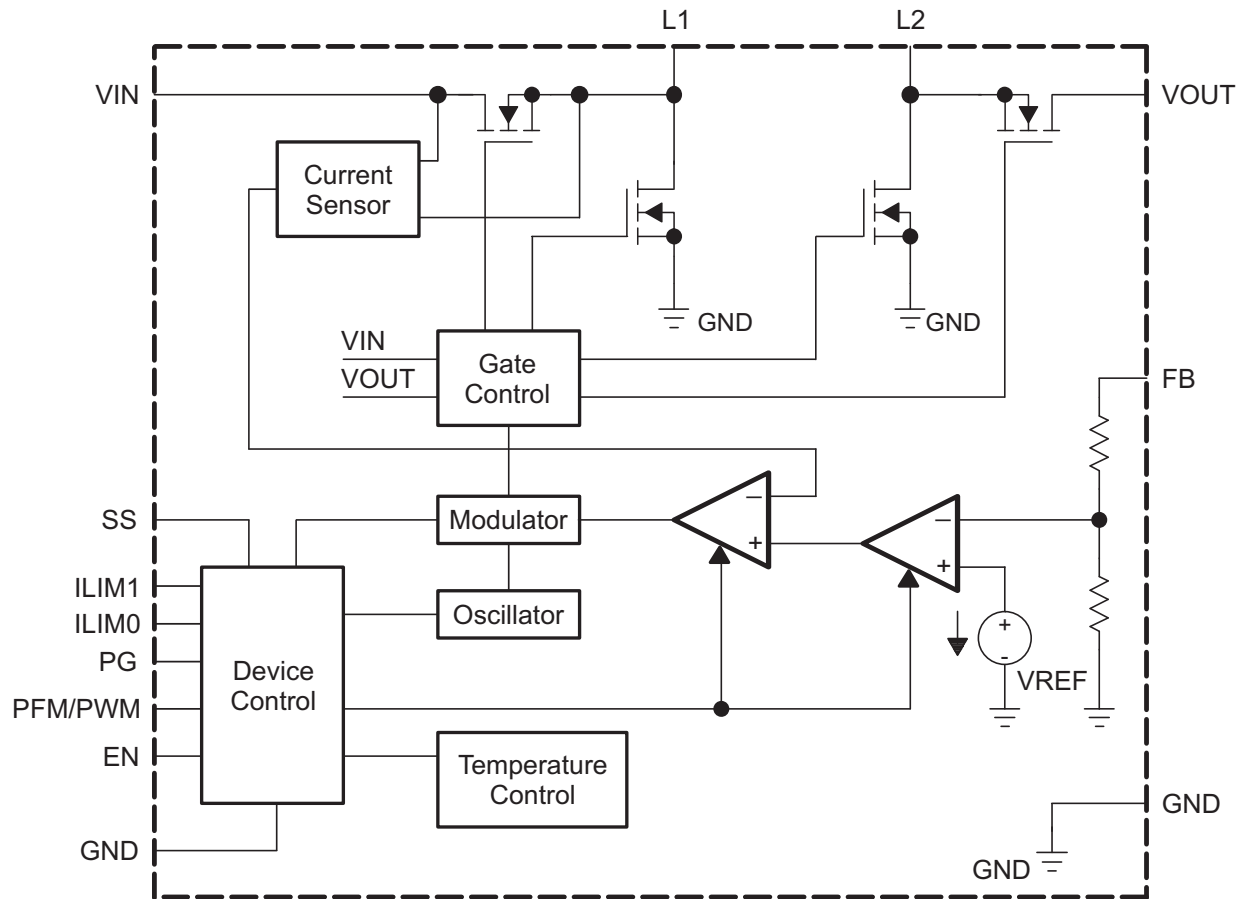


Figure 5. TPS63051 Block Diagram

8.3 Feature Description

8.3.1 Power Good

The TPS6305x devices have a PG output. The power good goes high impedance once the output is above 95% of the nominal voltage, and is driven low once the output voltage falls below typically 90% of the nominal voltage. The PG pin is an open drain output and is specified to sink up to 0.1 mA. The power good output requires a pullup resistor connecting to any voltage rail less than 5.5 V. The power good is valid as long as the converter is enabled and V_{IN} is present. The power good goes low when the device is in undervoltage lockout, in thermal shutdown or in current limit.

If EN is pulled low and one of the pins I_{LIM0} or I_{LIM1} is high, then the PG pin is low. If both pins, I_{LIM0} and I_{LIM1} are low, the PG is open drain. In this case the PG pin, follows its pullup voltage. If this is not desired, one of the two pins I_{LIM0} or I_{LIM1} , must be set high. [Table 1](#) lists the PG pin functionality.

Table 1. Power Good Settings

EN	ILIM1	ILIM0	PG
0	1	1	0
0	1	0	0
0	0	1	0
0	0	0	Open Drain

8.3.2 Overvoltage Protection

Overvoltage protection is implemented to limit the maximum output voltage. In case of overvoltage condition, the voltage amplifier regulates the output voltage to typically 6.7 V.

8.3.3 Undervoltage Lockout (UVLO)

To avoid mis-operation of the device at low input voltages, an undervoltage lockout is included. UVLO shuts down the device at input voltages lower than typically 1.7 V with a 200-mV hysteresis.

8.3.4 Thermal Shutdown

The device goes into thermal shutdown once the junction temperature exceeds typically 140°C with a 20°C hysteresis.

8.3.5 Soft Start

To minimize inrush current and output voltage overshoot during start up, the device has a soft start. At turn on, the input current raises monotonically until the output voltage reaches regulation. The TPS6305x devices charge the soft start capacitor, at the SS pin, with a constant current of typically 1 μ A. The input current follows the current used to charge the capacitor at the SS pin. The soft start operation is completed once the voltage at the SS pin has reached typically 1.3 V. [Figure 3](#) shows the value of the soft start capacitor in respect to the soft-start time.

The soft-start time is the time from when the EN pin is asserted to when the output voltage has reached 90% of its nominal value. There is typically a 100- μ s delay time from EN pin assertion to the start of the switching activity. The soft-start time depends on the load current, the input voltage, and the output capacitor. The soft-start time in boost mode is longer then the time in buck mode and it also depends on the load current, input voltage and output capacitor.

The soft-start time in [Figure 3](#) is referred to typical application with 10- μ F effective output capacitance.

The inductor current is able to increase and always assure a soft start unless a real short circuit is applied at the output.

8.3.6 Short Circuit Protection

The TPS6305x devices provide short circuit protection. When the output voltage does not increase above 1.2 V, a short circuit is detected and the output current is limited to 1.5 A.

8.4 Device Functional Modes

8.4.1 Control Loop Description

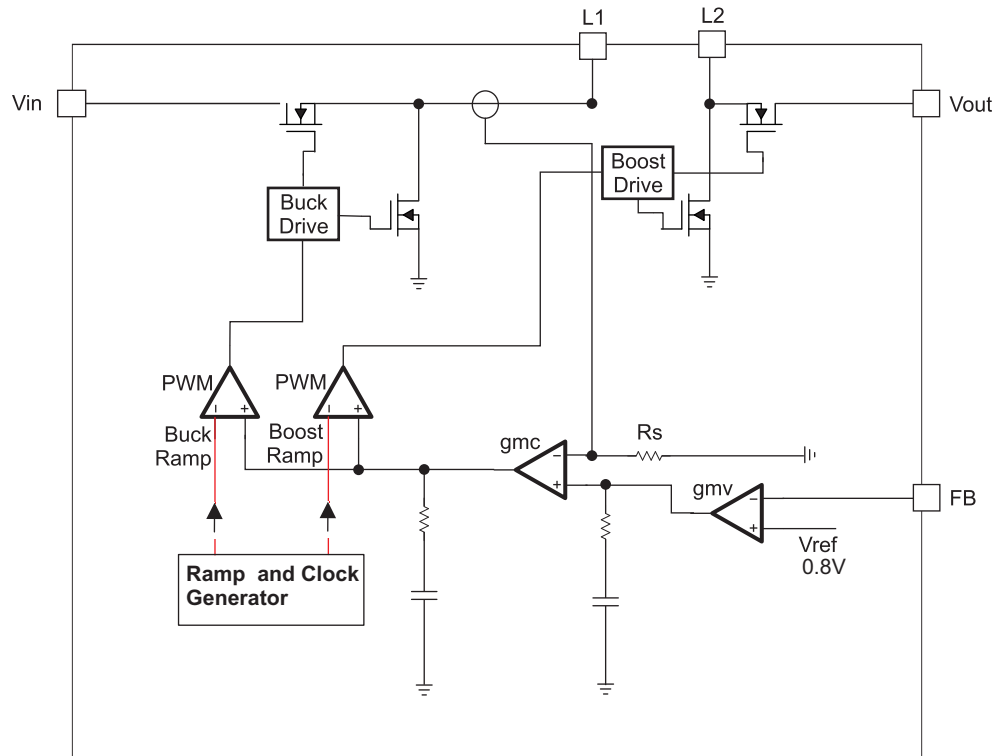


Figure 6. Average Current Mode Control

The controller circuit of the device is based on an average current mode topology. The average inductor current is regulated by a fast current regulator loop which is controlled by a voltage control loop. [Figure 6](#) shows the control loop.

The noninverting input of the transconductance amplifier, gm_v , is assumed to be constant. The output of gm_v defines the average inductor current. The inductor current is reconstructed by measuring the current through the high side buck MOSFET. This current corresponds exactly to the inductor current in boost mode. In buck mode the current is measured during the on time of the same MOSFET. During the off time, the current is reconstructed internally starting from the peak value at the end of the on time cycle. The average current and the feedback from the error amplifier gm_v forms the correction signal gm_c . This correction signal is compared to the buck and the boost sawtooth ramp giving the PWM signal. Depending on which of the two ramps the gm_c output crosses either the Buck or the Boost stage is initiated. When the input voltage is close to the output voltage, one buck cycle is always followed by a boost cycle. In this condition, no more than three cycles in a row of the same mode are allowed. This control method in the buck-boost region ensures a robust control and the highest efficiency.

Device Functional Modes (continued)

8.4.2 Power Save Mode Operation

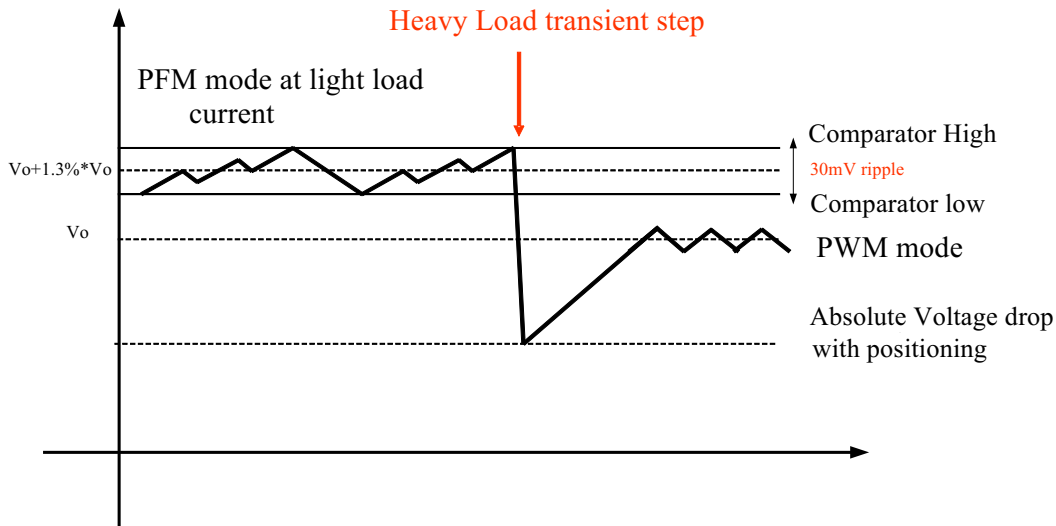


Figure 7. Power Save Mode Operation

Depending on the load current, the device works in PWM mode at load currents of approximately 350 mA or higher to provide the best efficiency over the complete load range. At lighter loads, the device switches automatically into Power Save Mode to reduce power consumption and extend battery life. The PFM/PWM pin is used to select between the two different operation modes. To enable Power Save Mode, the PFM/PWM pin must be set low.

During Power Save Mode, the part operates with a reduced switching frequency and lowest supply current to maintain high efficiency. The output voltage is monitored with a comparator at every clock cycle by the thresholds comp low and comp high. When the device enters Power Save Mode, the converter stops operating and the output voltage drops. The slope of the output voltage depends on the load and the output capacitance. When the output voltage reaches the comp low threshold, at the next clock cycle the device ramps up the output voltage again, by starting operation. Operation can last for one or several pulses until the comp high threshold is reached. At the next clock cycle, if the load is still lower than 150 mA, the device switches off again and the same operation is repeated. If at the next clock cycle the load is above 150 mA, the device automatically switches to PWM mode.

To keep high efficiency in PFM mode, there is only one comparator active to keep the output voltage regulated. The AC ripple in this condition is increased, compared to the PWM mode. The amplitude of this voltage ripple in the worst case scenario is 50 mV peak to peak, (typically 30 mV peak-to-peak), with 10 μ F of effective output capacitance. To avoid a critical voltage drop when switching from 0 A to full load, the output voltage in PFM mode is typically 1.5% above the nominal value in PWM mode. This is called Dynamic Voltage Positioning and allows the converter to operate with a small output capacitor and still have a low absolute voltage drop during heavy load transients.

Power Save Mode is disabled by setting the PFM/PWM pin high.

8.4.3 Adjustable Current Limit

The TPS6305x devices have an internal user programmable current limit that monitors the input current during start-up. This prevents high inrush current protecting the device and the application. During start-up the input current does not exceed the current limit that is set by I_{LIM0} pin and I_{LIM1} pin. Depending on the logic level applied at these two pins, switching between four different current limit-levels is possible. The variation of those values over input voltage and temperature is shown in Figure 1 through Figure 2. Adjusting the soft-start time further using the soft-start capacitor is possible.

I_{LIM0} and I_{LIM1} set the current limit as listed in Table 2.

Device Functional Modes (continued)

Table 2. Adjustable Current Limit

ILIM1	ILIM0	CURRENT LIMIT SET (WCSP)	CURRENT LIMIT SET (HotRod)
Low	Low	$0.4 \times I_{IN_MAX}$	Not Available
Low	High	$0.5 \times I_{IN_MAX}$	Not Available
High	Low	$0.65 \times I_{IN_MAX}$	$0.65 \times I_{IN_MAX}$
High	High	I_{IN_MAX}	I_{IN_MAX}

The I_{LIM0} , I_{LIM1} pins can be changed during operation.

Given the curves provided in [Figure 1](#) through [Figure 2](#), calculating the output current in the different condition in boost mode is possible using [Equation 1](#) and [Equation 2](#) and in buck mode using [Equation 3](#) and [Equation 4](#).

$$\text{Duty Cycle Boost} \quad D = \frac{V_{OUT} - V_{IN}}{V_{OUT}} \quad (1)$$

$$\text{Output Current Boost} \quad I_{OUT} = \eta \times I_{IN} (1-D)$$

where

- η = Estimated converter efficiency (use the number from the efficiency curves or 0.9 as an assumption)
- I_{IN} = Minimum average input current ([Figure 2](#) to [Figure 2](#))

$$\text{Duty Cycle Buck} \quad D = \frac{V_{OUT}}{V_{IN}} \quad (3)$$

$$\text{Output Current Buck} \quad I_{OUT} = (\eta \times I_{IN}) / D$$

where

- For η , use the number from the efficiency curves or 0.9 as an assumption.

8.4.4 Device Enable

The device starts operation when the EN pin is set high. The device enters shutdown mode when the EN pin is set low. In shutdown mode, the regulator stops switching, all internal control circuitry is switched off, and the load is disconnected from the input.

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers must validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TPS6305x is a high efficiency, low quiescent current buck-boost converter suitable for applications where the input voltage is higher or lower than the output voltage. Continuous output current can go as high as 500 mA in boost mode and as high as 1 A in buck mode. The maximum average current in the switches is limited to a typical value of 1 A.

The efficiency measurements

9.2 Typical Application

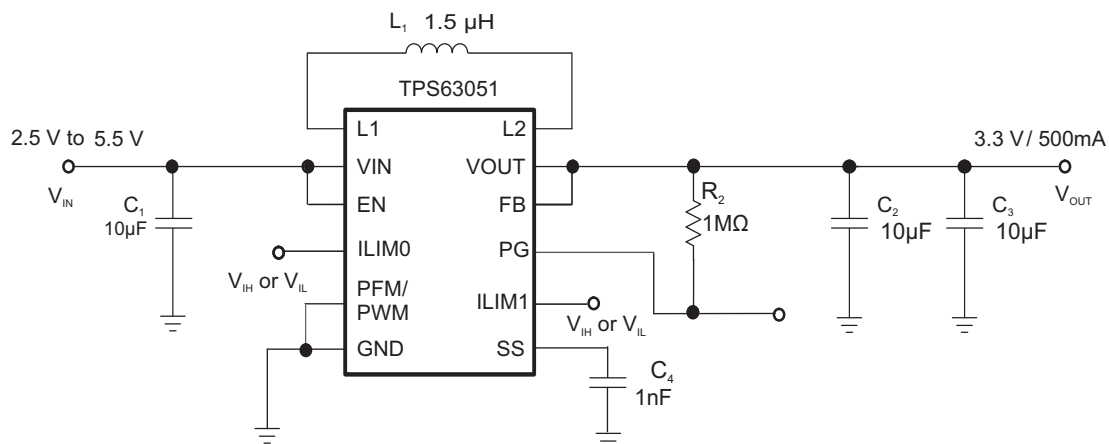


Figure 8. Parameter Measurement Circuit (WCSP)

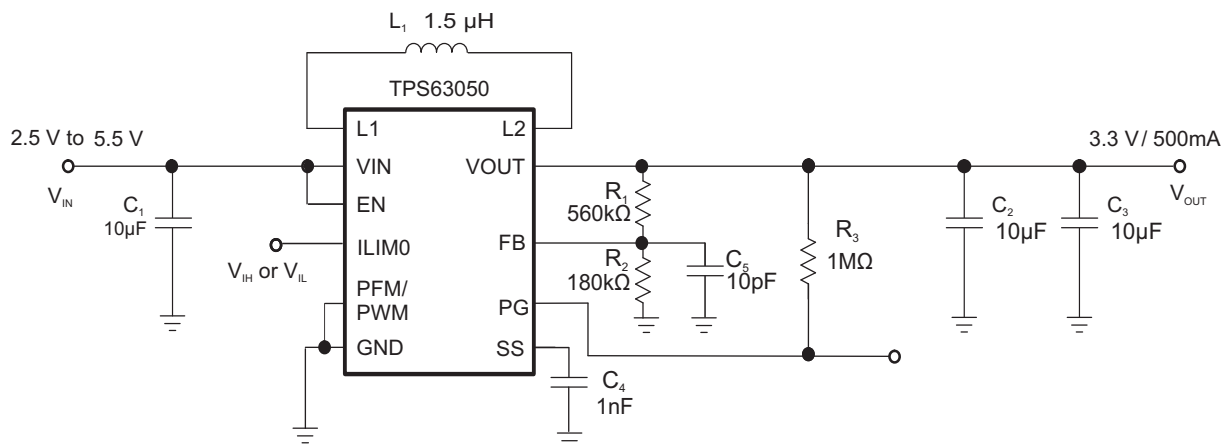


Figure 9. Parameter Measurement Circuit (HotRod)

9.2.1 Design Requirements

The design guidelines provide a component selection to operate the device within the recommended operating conditions.

Typical Application (continued)

9.2.2 Detailed Design Procedure

9.2.2.1 Custom Design With WEBENCH® Tools

[Click here](#) to create a custom design using the TPS63050 device with the WEBENCH® Power Designer.

[Click here](#) to create a custom design using the TPS63051 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

The first step is the selection of the output filter components, listed in [Table 3](#). To simplify this process, [Table 4](#) outlines possible inductor and capacitor value combinations.

Table 3. Components for Application Characteristic Curves

REFERENCE	DESCRIPTION	MANUFACTURER
	TPS6305x	Texas Instruments
L1	1.5 μ H, 2.1 A, 108 m Ω	1269AS-H-1R5M, TOKO
C1, C2, C3	10 μ F, 6.3 V, 0603, X5R ceramic	GRM188R60J106ME84D, Murata
C4	C_{SS}	
C5	10pF, only needed for the HotRod package version to filter ground noise when using external resistor divider	
R1	Depending on the output voltage of TPS6305x, 0 Ω with TPS63051	
R2	Depending on the output voltage of TPS6305x, not used with TPS63051	
R3	1 M Ω	

9.2.2.2 Output Filter Design

Table 4. Matrix of Output Capacitor and Inductor Combinations

NOMINAL INDUCTOR VALUE [μ H] ⁽¹⁾	NOMINAL OUTPUT CAPACITOR VALUE [μ F] ⁽²⁾				
	10	20	44	66	100
1			+	+	+
1.5	+	+(3)	+	+	+
2.2			+	+	+

(1) Inductor tolerance and current de-rating is anticipated. The effective inductance can vary by 20% and –30%.

(2) Capacitance tolerance and bias voltage de-rating is anticipated. The effective capacitance can vary by 20% and –50%.

(3) Typical application. Other check mark indicates recommended filter combinations

9.2.2.3 Inductor Selection

The inductor selection is affected by several parameter like inductor ripple current, output voltage ripple, transition point into power save mode, and efficiency. See [Table 5](#) for typical inductors.

Table 5. List of Recommended Inductors

INDUCTOR VALUE	COMPONENT SUPPLIER ⁽¹⁾	SIZE (L × W × H mm)	Isat / DCR
1 µH	TOKO 1286AS-H-1R0M	2 × 1.6 × 1.2	2.1 A / 68 mΩ
1.5 µH	TOKO, 1286AS-H-1R5M	2 × 1.6 × 1.2	2.5 A / 95 mΩ
1.5 µH	TOKO, 1269AS-H-1R5M	2.5 × 2 × 1	2.1 A / 90 mΩ
2.2 µH	TOKO 1286AS-H-2R2M	2 × 1.6 × 1.2	2 A / 160 mΩ

(1) See the [Third Party Product Disclaimer](#) section.

For high efficiencies, the inductor must have a low dc resistance to minimize conduction losses. Especially at high-switching frequencies, the core material has a high impact on efficiency. When using small chip inductors, the efficiency is reduced mainly due to higher inductor core losses. This needs to be considered when selecting the appropriate inductor. The inductor value determines the inductor ripple current. The larger the inductor value, the smaller the inductor ripple current and the lower the conduction losses of the converter. Conversely, larger inductor values cause a slower load transient response. To avoid saturation of the inductor, the peak current for the inductor in steady state operation is calculated using [Equation 6](#). Only the equation which defines the switch current in boost mode is shown, because this provides the highest value of current and represents the critical current value for selecting inductor.

$$\text{Duty Cycle Boost} \quad D = \frac{V_{OUT} - V_{IN}}{V_{OUT}}$$

where

- D = Duty Cycle in Boost mode (5)

$$I_{PEAK} = \frac{I_{OUT}}{\eta \times (1 - D)} + \frac{V_{IN} \times D}{2 \times f \times L}$$

where

- η = Estimated converter efficiency (use the number from the efficiency curves or 0.80 as an assumption)
- f = Converter switching frequency (typical 2.5MHz)
- L = Inductor value (6)

NOTE

The calculation must be done for the minimum input voltage that is possible to have in boost mode.

Calculating the maximum inductor current using the actual operating conditions gives the minimum saturation current of the inductor needed. It's recommended to choose an inductor with a saturation current 20% higher than the value calculated using [Equation 6](#). Possible inductors are listed in [Table 5](#).

9.2.2.4 Capacitor selection

9.2.2.4.1 Input Capacitor

At least a 10-µF input capacitor is recommended to improve line transient behavior of the regulator and EMI behavior of the total power supply circuit. An X5R or X7R ceramic capacitor placed as close as possible to the VIN and GND pins of the IC is recommended. This capacitance can be increased without limit.

9.2.2.4.2 Output Capacitor

Use of small ceramic capacitors placed as close as possible to the VOUT and PGND pins of the IC, is recommended for the output capacitor. The recommended nominal output capacitance value is 10 µF with a variance as outlined in [Table 4](#).

There is also no upper limit for the output capacitance value. Larger capacitors causes lower output voltage ripple as well as lower output voltage drop during load transients.

9.2.2.5 Setting the Output Voltage

When the adjustable output voltage version TPS63050 is used, the output voltage is set by the external resistor divider. The resistor divider must be connected between VOUT, FB and GND. When the output voltage is regulated properly, the typical value of the voltage at the FB pin is 800 mV. The current through the resistive divider must be 100 times greater than the current into the FB pin. The typical current into the FB pin is 0.1 μ A, and the voltage across the resistor between FB and GND, R_2 , is typically 800 mV. Based on these two values, the recommended value for R_2 must be lower than 200 k Ω , in order to set the divider current at 3 μ A or higher. It is recommended to keep the value for this resistor in the range of 200 k Ω . The value of the resistor connected between VOUT and FB, R_1 , depending on the needed output voltage (V_{OUT}), can be calculated using [Equation 7](#):

$$R1 = R2 \times \left(\frac{V_{OUT}}{V_{FB}} - 1 \right) \quad (7)$$

When using the HotRod package version of the TPS63050, it is recommended to add capacitor C_5 , as shown in [Figure 9](#). The capacitor on the feedback node is required to help filtering ground noise and matching the efficiency result shown in the [Application Curves](#) paragraph.

9.2.3 Application Curves

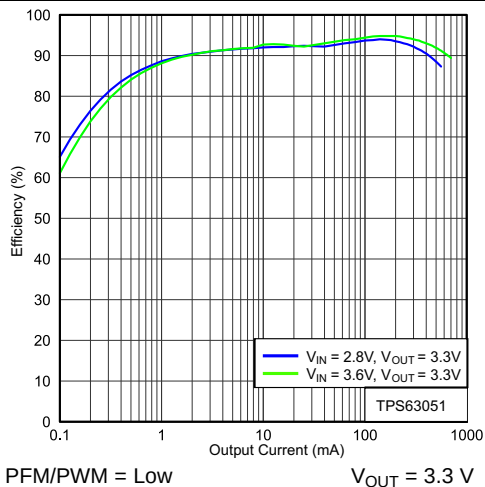


Figure 10. Efficiency vs Output Current

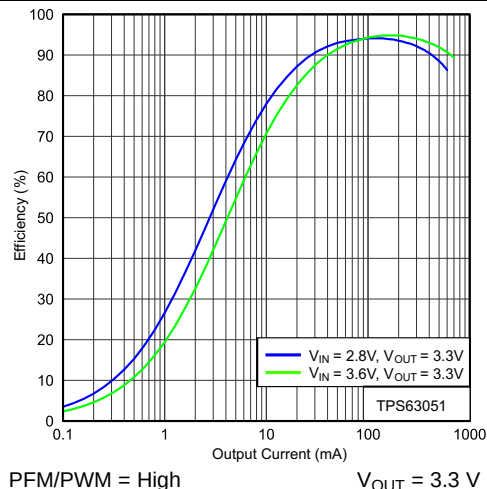


Figure 11. Efficiency vs Output Current

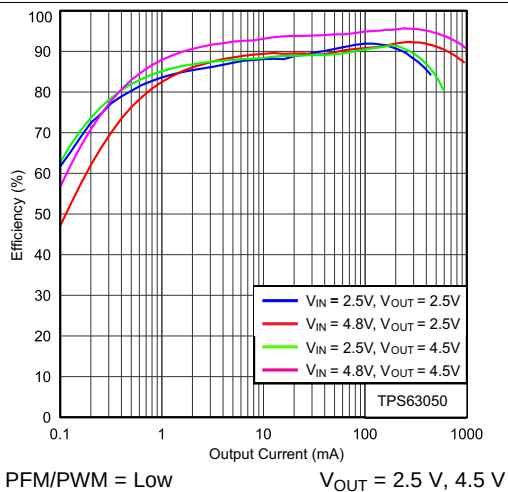


Figure 12. Efficiency vs Output Current

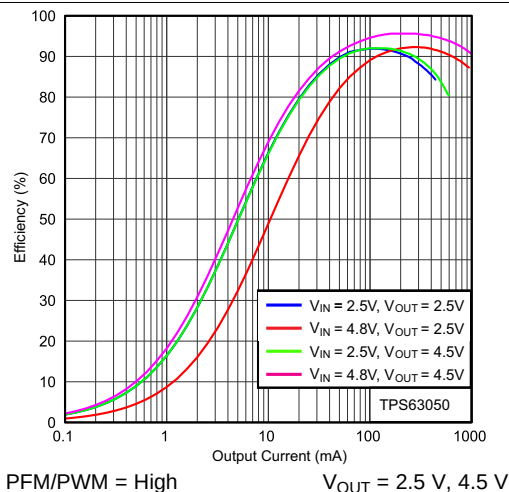


Figure 13. Efficiency vs Output Current

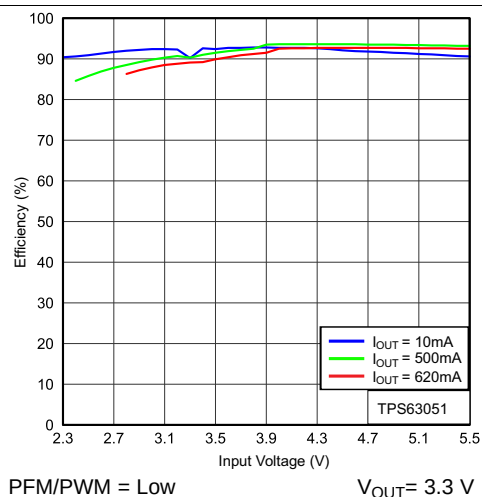


Figure 14. Efficiency vs Input Voltage

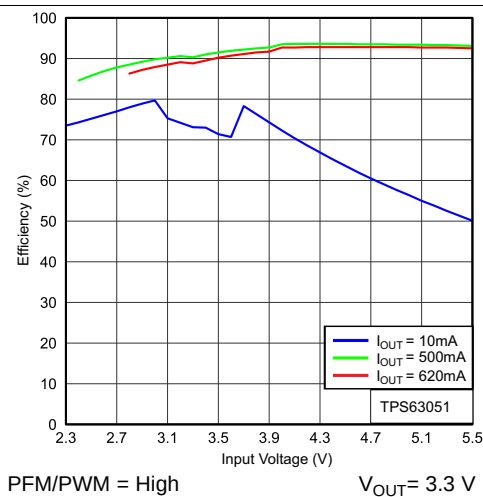


Figure 15. Efficiency vs Input Voltage

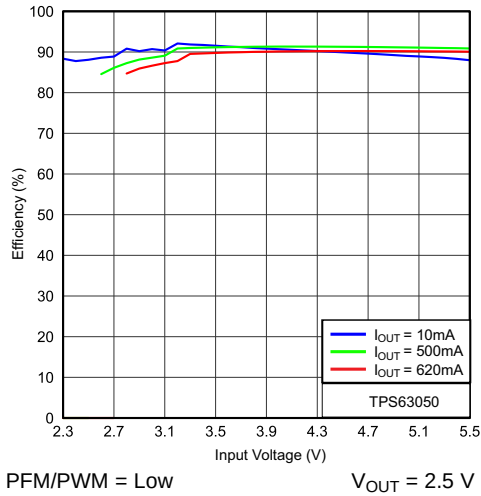


Figure 16. Efficiency vs Input Voltage

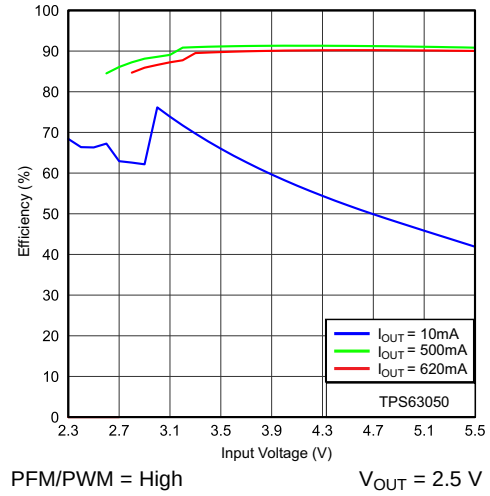


Figure 17. Efficiency vs Input Voltage

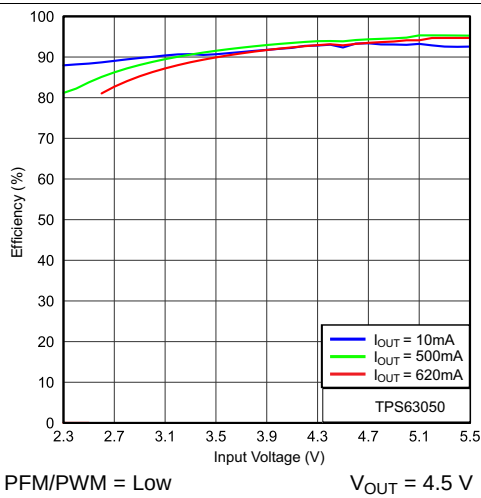


Figure 18. Efficiency vs Input Voltage

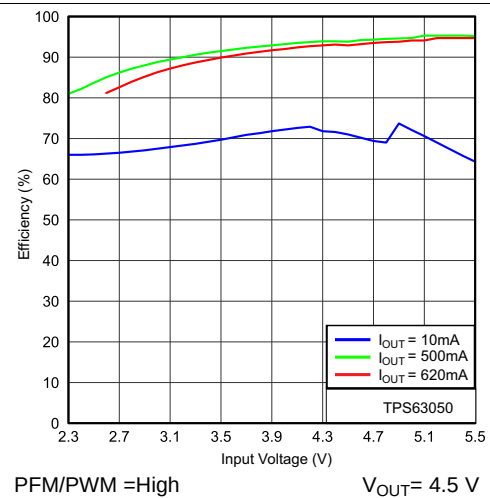


Figure 19. Efficiency vs Input Voltage

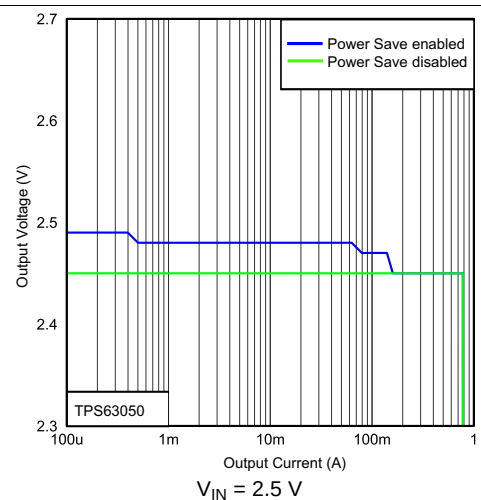


Figure 20. Output Voltage vs Output Current

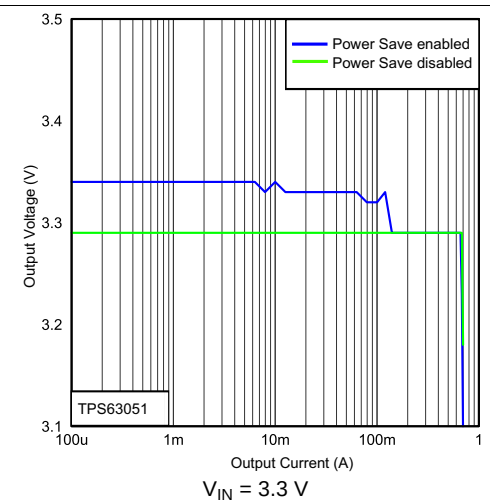


Figure 21. Output Voltage vs Output Current

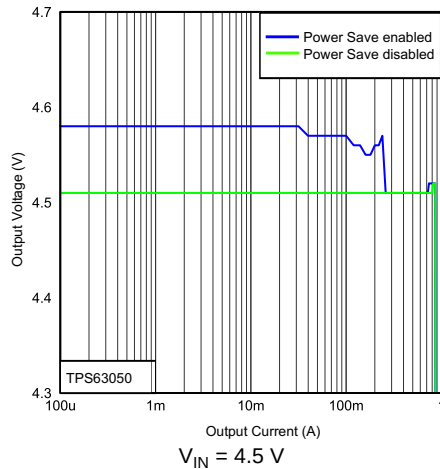


Figure 22. Output Voltage vs Output Current

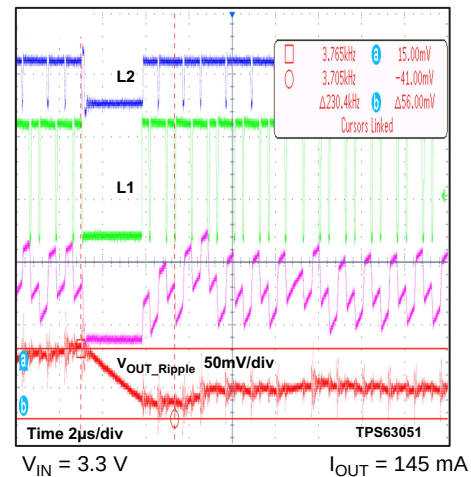


Figure 23. Output Voltage ripple in Buck-Boost mode and PFM to PWM transition

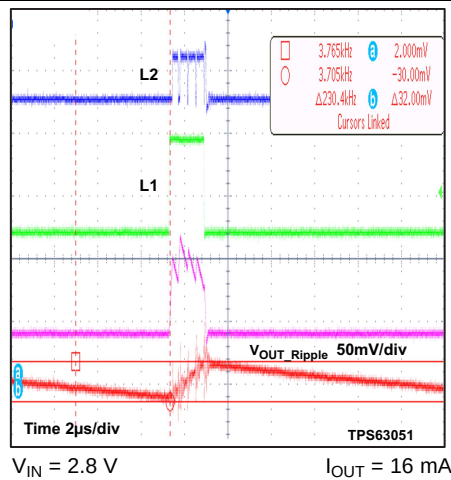


Figure 24. Output Voltage Ripple in Boost Mode and PFM to PWM Transition

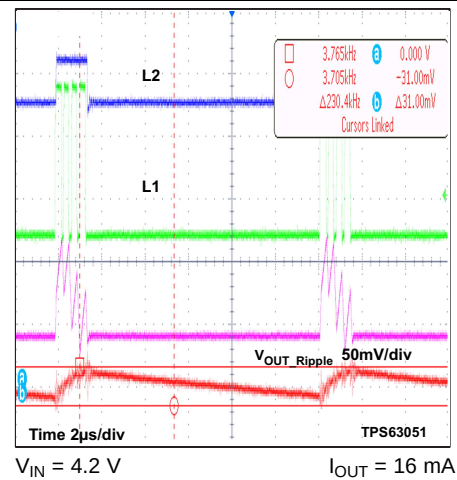


Figure 25. Output Voltage Ripple in Buck Mode and PFM to PWM Transition

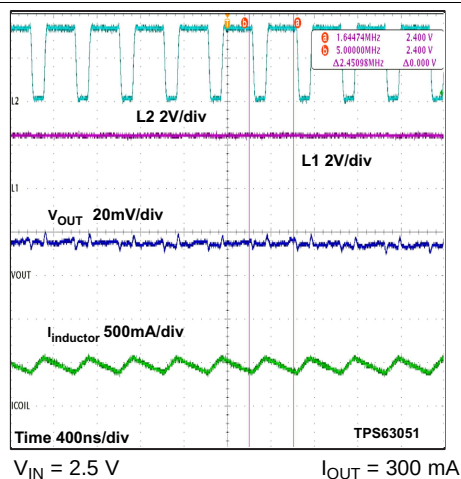


Figure 26. Switching Waveform in Boost Mode and PWM

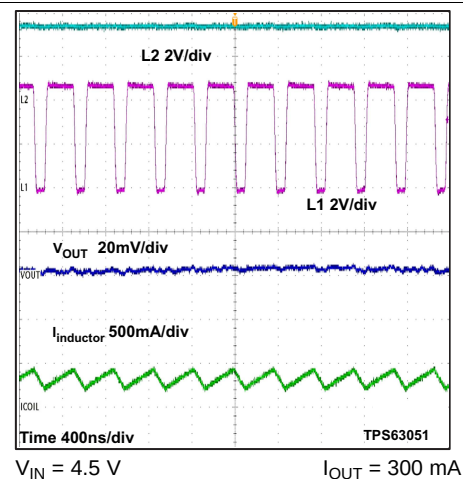


Figure 27. Switching Waveform in Buck Mode and PWM

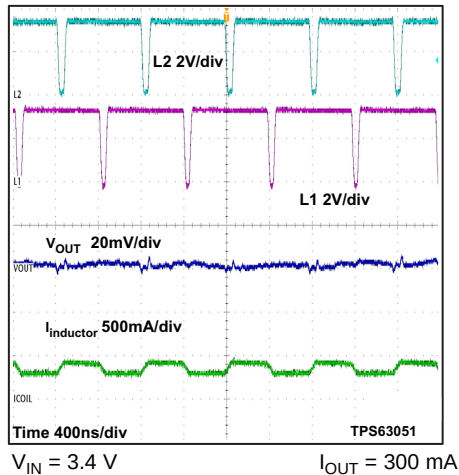


Figure 28. Switching Waveform in Buck-Boost Mode and PWM

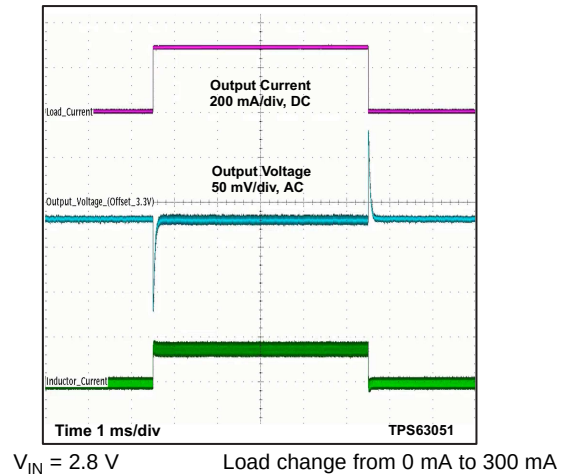


Figure 29. Load Transient Response

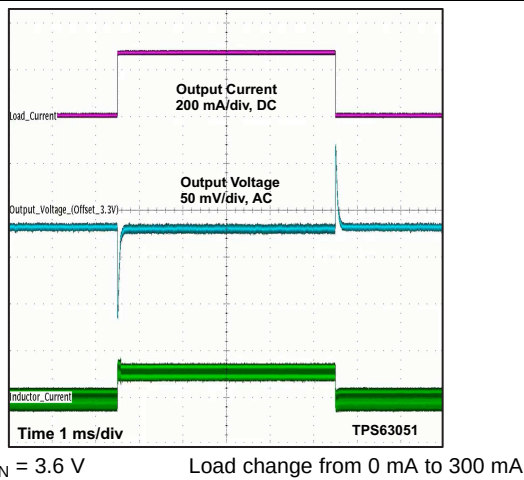


Figure 30. Load Transient Response

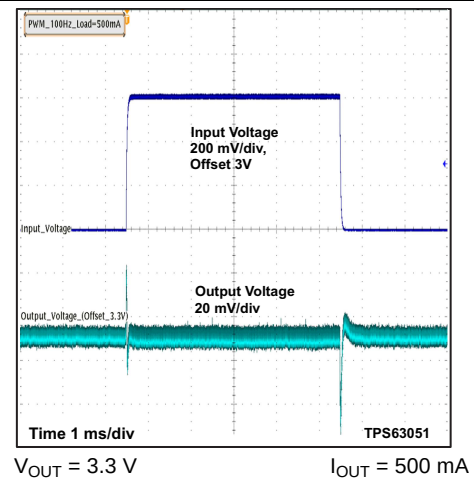


Figure 31. Line Transient Response

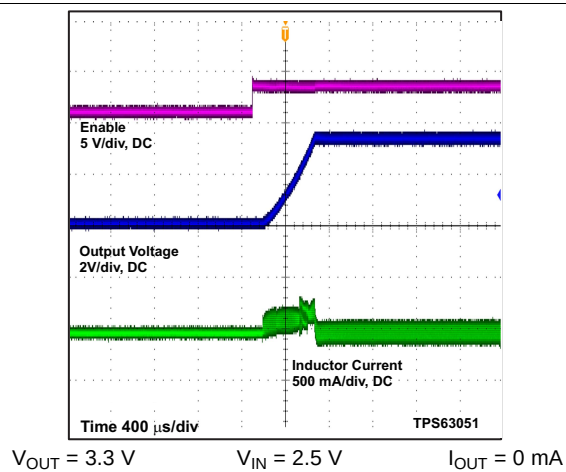


Figure 32. Start Up After Enable

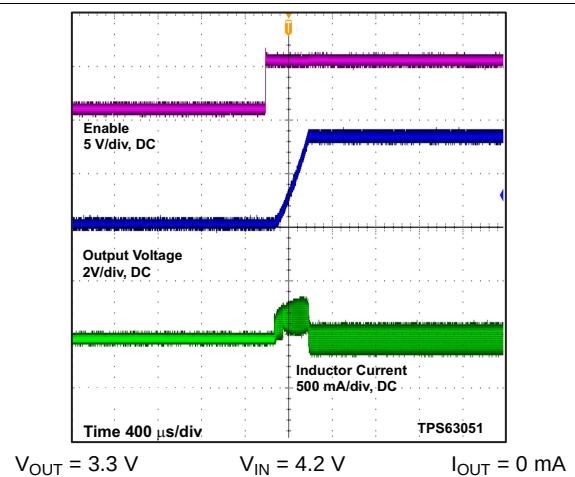


Figure 33. Start Up After Enable

10 Power Supply Recommendations

The TPS6305x device family has no special requirements for its input power supply. The input power supply output current needs to be rated according to the supply voltage, output voltage and output current of the TPS6305x devices.

11 Layout

11.1 Layout Guidelines

The PCB layout is an important step to maintain the high performance of the TPS6305x devices.

- Place input and output capacitors as close as possible to the IC. Traces need to be kept short. Routing wide and direct traces to the input and output capacitor results in low-trace resistance and low parasitic inductance.
- Use a common-power GND.
- The sense trace connected to FB is signal trace. Keep these traces away from L1 and L2 nodes.
- For the HotRod package option it is important to add a capacitor between FB node and ground to filter ground noise and to match efficiency results documented in these datasheet.

11.2 Layout Example (WCSP)

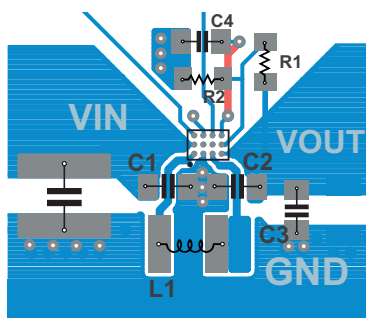


Figure 34. TPS6305x Layout (WCSP)

11.3 Layout Example (HotRod)

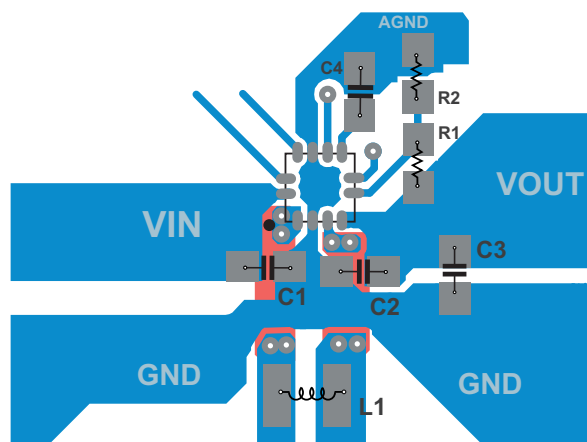


Figure 35. TPS6305x Layout (HotRod)

11.4 Thermal Considerations

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the powerdissipation limits of a given component.

Two basic approaches for enhancing thermal performance are listed below:

- Improving the power dissipation capability of the PCB design
- Introducing airflow in the system

For more details on how to use the thermal parameters, see the application notes: *Thermal Characteristics* (SZZA017), and *Semiconductor and IC Package Thermal Metrics* (SPRA953)

12 器件和文档支持

12.1 使用 WEBENCH® 工具创建定制设计

[单击此处](#)，使用 TPS63050 器件并借助 WEBENCH® 电源设计器创建定制设计方案。

[单击此处](#)，使用 TPS63051 器件并借助 WEBENCH® 电源设计器创建定制设计方案。

- 首先输入输入电压 (V_{IN})、输出电压 (V_{OUT}) 和输出电流 (I_{OUT}) 要求。
- 使用优化器拨盘优化该设计的关键参数，如效率、尺寸和成本。
- 将生成的设计与德州仪器 (TI) 的其他可行的解决方案进行比较。

WEBENCH 电源设计器可提供定制原理图以及罗列实时价格和组件供货情况的物料清单。

在多数情况下，可执行以下操作：

- 运行电气仿真，观察重要波形以及电路性能
- 运行热性能仿真，了解电路板热性能
- 将定制原理图和布局方案以常用 CAD 格式导出
- 打印设计方案的 PDF 报告并与同事共享

有关 WEBENCH 工具的详细信息，请访问 www.ti.com.cn/WBENCH。

12.2 器件支持

12.2.1 第三方产品免责声明

TI 发布的与第三方产品或服务有关的信息，不能构成与此类产品或服务或保修的适用性有关的认可，不能构成此类产品或服务单独或与任何 TI 产品或服务一起的表示或认可。

12.3 相关链接

下表列出了快速访问链接。类别包括技术文档、支持与社区资源、工具和软件，以及申请样片或购买产品的快速链接。

表 6. 相关链接

器件	产品文件夹	样片与购买	技术文档	工具与软件	支持和社区
TPS63050	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
TPS63051	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处

12.4 接收文档更新通知

要接收文档更新通知，请导航至 TI.com.cn 上的器件产品文件夹。单击右上角的 [通知我](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

12.5 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.6 商标

E2E is a trademark of Texas Instruments.

WEBENCH is a registered trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.7 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

12.8 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

重要声明和免责声明

TI 均以“原样”提供技术性 & 可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证其中不含任何瑕疵，且不做任何明示或暗示的担保，包括但不限于对适销性、适合某特定用途或不侵犯任何第三方知识产权的暗示担保。

所述资源可供专业开发人员应用 TI 产品进行设计使用。您将对以下行为独自承担全部责任：(1) 针对您的应用选择合适的 TI 产品；(2) 设计、验证并测试您的应用；(3) 确保您的应用满足相应标准以及任何其他安全、安保或其他要求。所述资源如有变更，恕不另行通知。TI 对您使用所述资源的授权仅限于开发资源所涉及 TI 产品的相关应用。除此之外不得复制或展示所述资源，也不提供其它 TI 或任何第三方的知识产权授权许可。如因使用所述资源而产生任何索赔、赔偿、成本、损失及债务等，TI 对此概不负责，并且您须赔偿由此对 TI 及其代表造成的损害。

TI 所提供产品均受 TI 的销售条款 (<http://www.ti.com.cn/zh-cn/legal/termsofsale.html>) 以及 [ti.com.cn](http://www.ti.com.cn) 上或随附 TI 产品提供的其他可适用条款的约束。TI 提供所述资源并不扩展或以其他方式更改 TI 针对 TI 产品所发布的可适用的担保范围或担保免责声明。

邮寄地址：上海市浦东新区世纪大道 1568 号中建大厦 32 楼，邮政编码：200122
Copyright © 2020 德州仪器半导体技术（上海）有限公司

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS63050RMWR	ACTIVE	VQFN-HR	RMW	12	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	F630	Samples
TPS63050RMWT	ACTIVE	VQFN-HR	RMW	12	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	F630	Samples
TPS63050YFFR	ACTIVE	DSBGA	YFF	12	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 125	63050	Samples
TPS63050YFFT	ACTIVE	DSBGA	YFF	12	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 125	63050	Samples
TPS63051RMWR	ACTIVE	VQFN-HR	RMW	12	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	F631	Samples
TPS63051RMWT	ACTIVE	VQFN-HR	RMW	12	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	F631	Samples
TPS63051YFFR	ACTIVE	DSBGA	YFF	12	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 125	63051	Samples
TPS63051YFFT	ACTIVE	DSBGA	YFF	12	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 125	63051	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

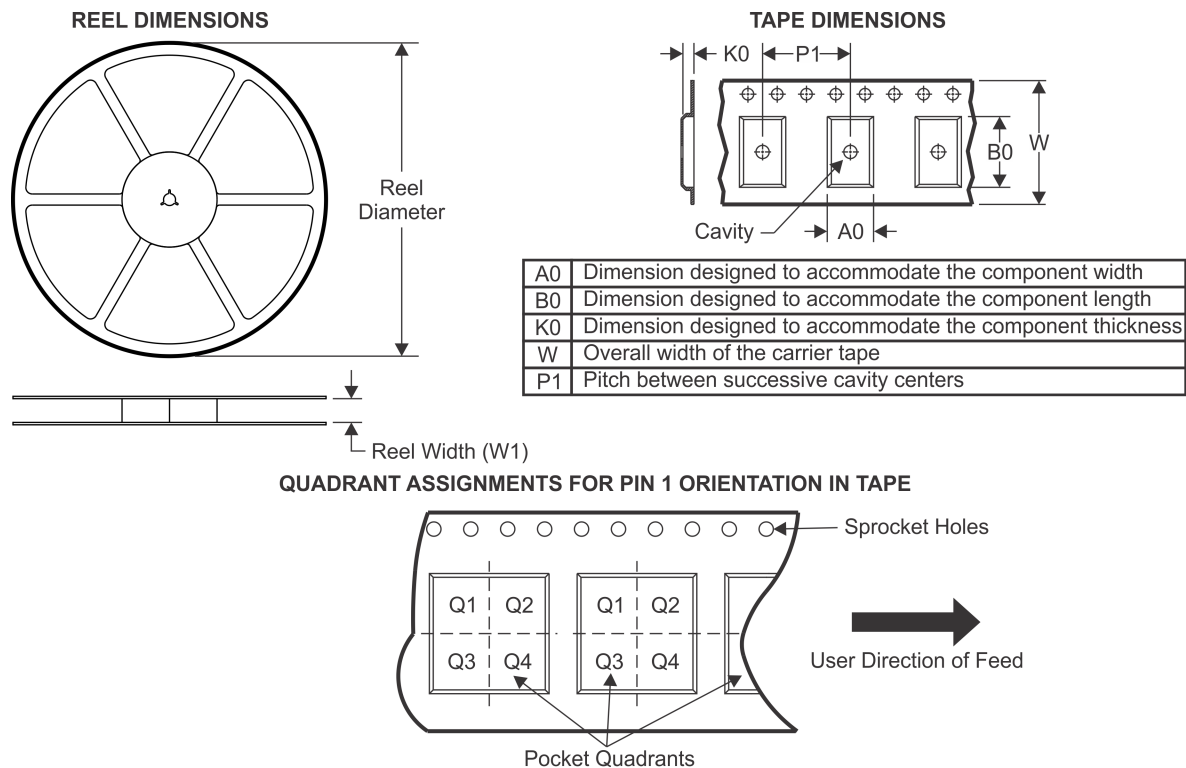
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

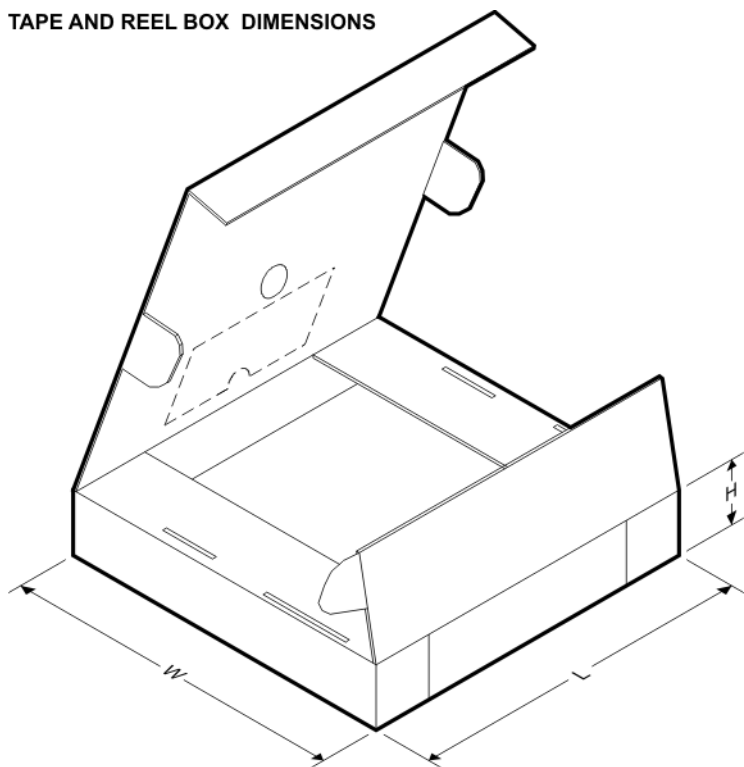
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS63050RMWR	VQFN-HR	RMW	12	3000	180.0	8.4	2.8	2.8	1.0	4.0	8.0	Q2
TPS63050RMWT	VQFN-HR	RMW	12	250	180.0	8.4	2.8	2.8	1.0	4.0	8.0	Q2
TPS63050YFFR	DSBGA	YFF	12	3000	180.0	8.4	1.39	1.79	0.7	4.0	8.0	Q1
TPS63050YFFT	DSBGA	YFF	12	250	180.0	8.4	1.39	1.79	0.7	4.0	8.0	Q1
TPS63051RMWR	VQFN-HR	RMW	12	3000	180.0	8.4	2.8	2.8	1.0	4.0	8.0	Q2
TPS63051RMWT	VQFN-HR	RMW	12	250	180.0	8.4	2.8	2.8	1.0	4.0	8.0	Q2
TPS63051YFFR	DSBGA	YFF	12	3000	180.0	8.4	1.39	1.79	0.7	4.0	8.0	Q1
TPS63051YFFT	DSBGA	YFF	12	250	180.0	8.4	1.39	1.79	0.7	4.0	8.0	Q1

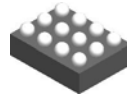
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS63050RMWR	VQFN-HR	RMW	12	3000	182.0	182.0	20.0
TPS63050RMWT	VQFN-HR	RMW	12	250	182.0	182.0	20.0
TPS63050YFFR	DSBGA	YFF	12	3000	182.0	182.0	20.0
TPS63050YFFT	DSBGA	YFF	12	250	182.0	182.0	20.0
TPS63051RMWR	VQFN-HR	RMW	12	3000	182.0	182.0	20.0
TPS63051RMWT	VQFN-HR	RMW	12	250	182.0	182.0	20.0
TPS63051YFFR	DSBGA	YFF	12	3000	182.0	182.0	20.0
TPS63051YFFT	DSBGA	YFF	12	250	182.0	182.0	20.0

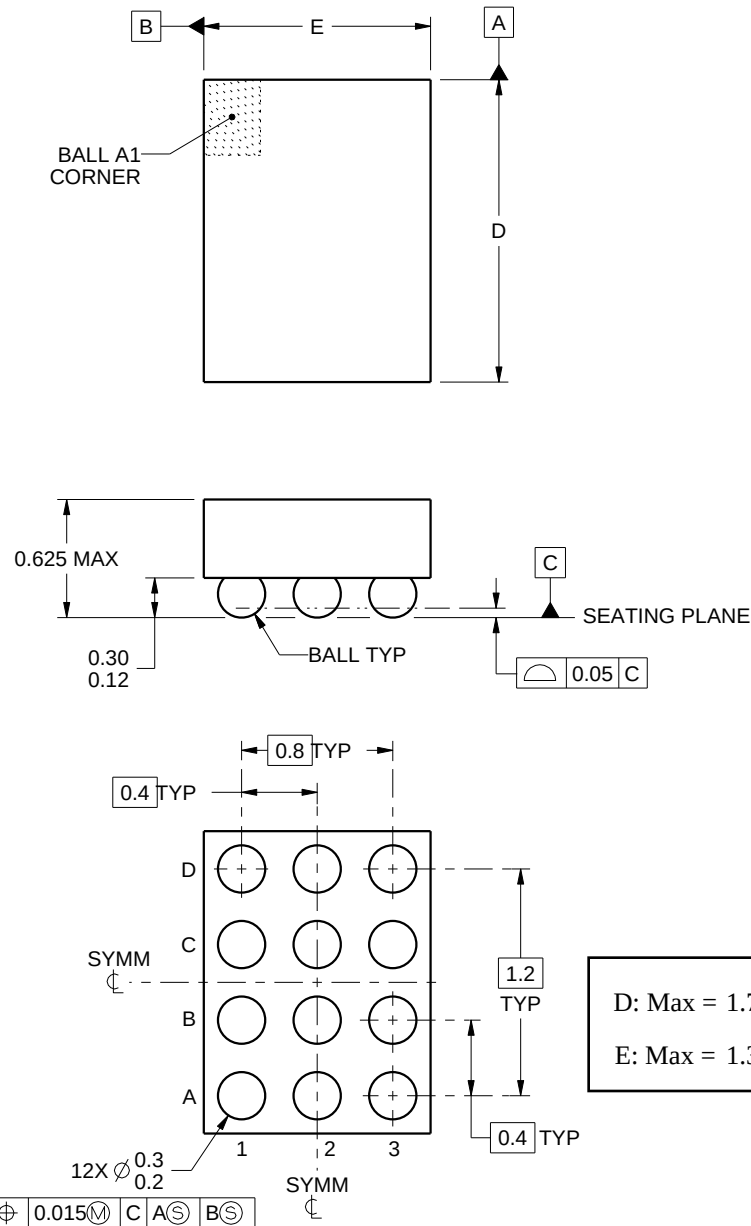
YFF0012



PACKAGE OUTLINE

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



4222191/A 07/2015

NOTES:

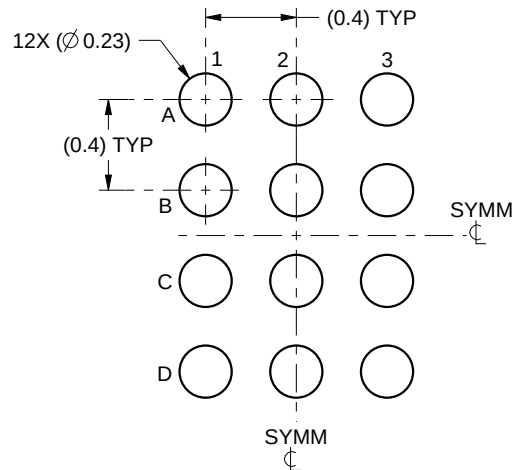
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

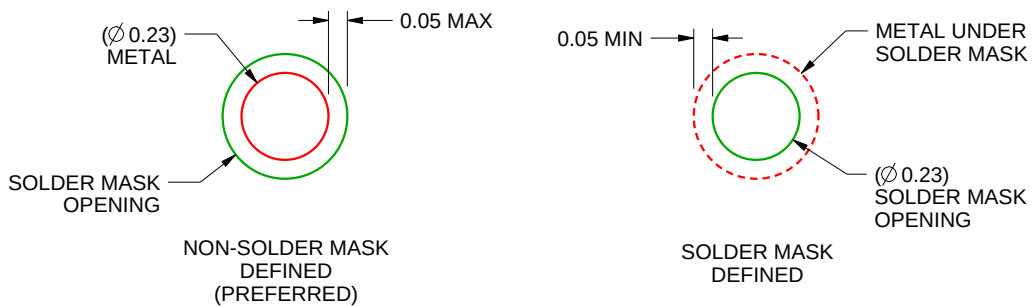
YFF0012

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE
SCALE:30X



SOLDER MASK DETAILS
NOT TO SCALE

4222191/A 07/2015

NOTES: (continued)

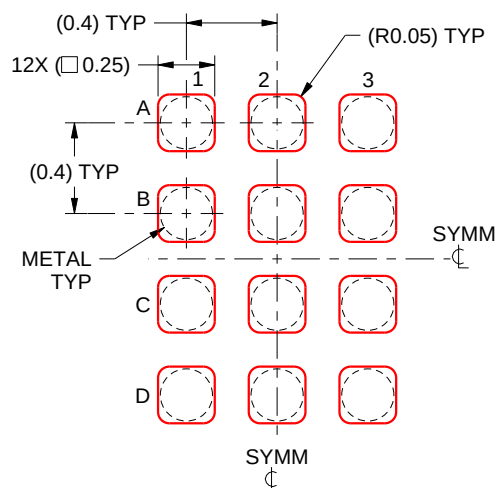
3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).

EXAMPLE STENCIL DESIGN

YFF0012

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



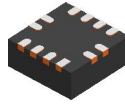
SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:30X

4222191/A 07/2015

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

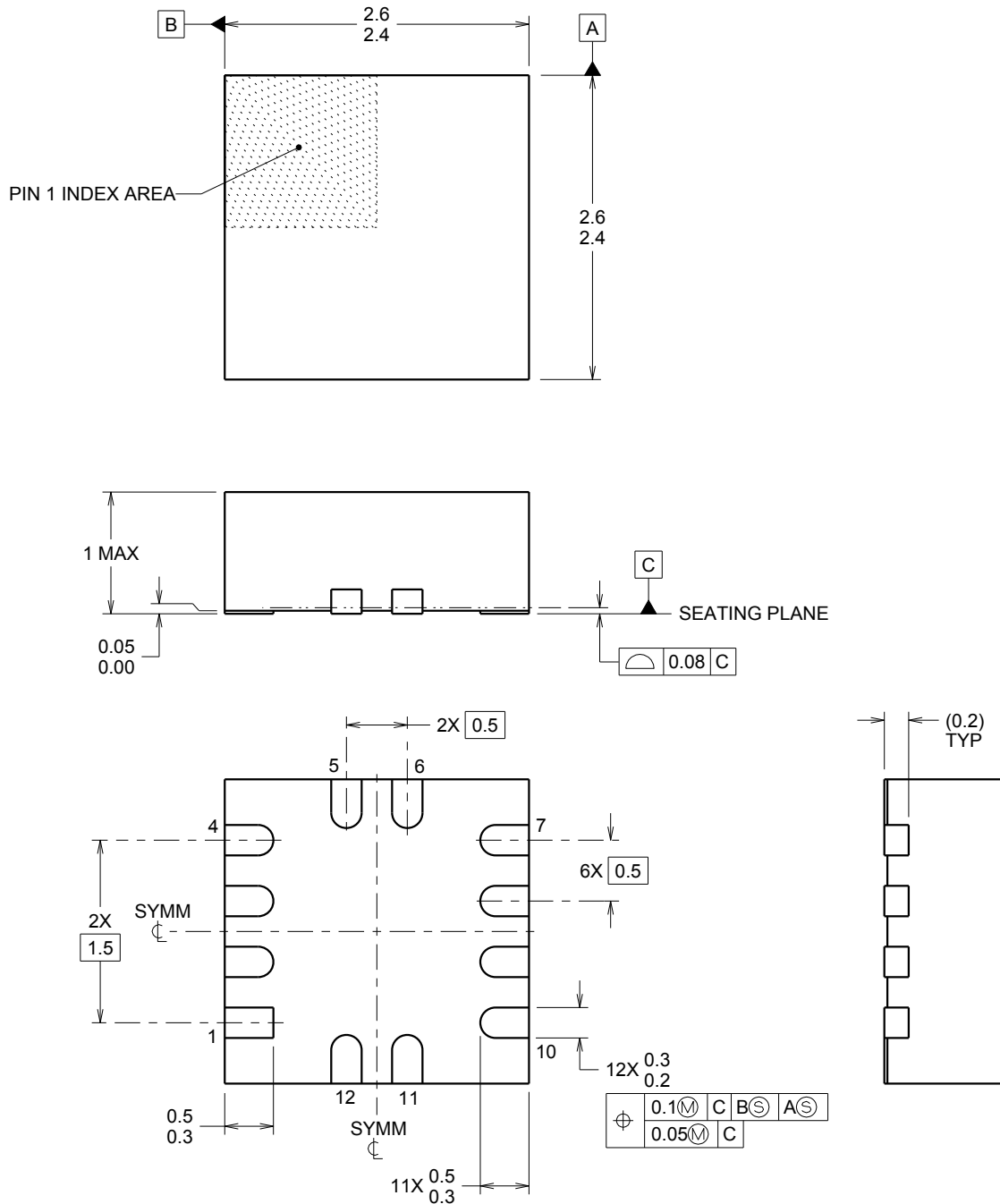
RMW0012A



PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLAT PACK - NO LEAD



4221400/A 07/2014

NOTES:

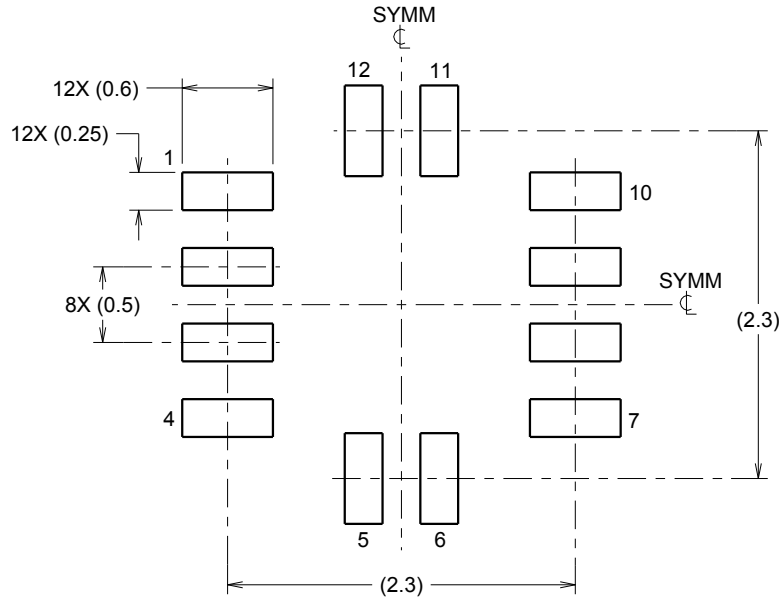
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

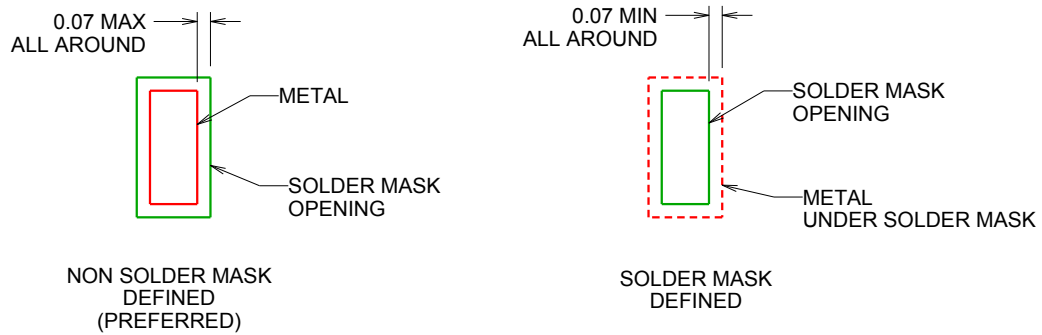
RMW0012A

VQFN - 1 mm max height

PLASTIC QUAD FLAT PACK - NO LEAD



LAND PATTERN EXAMPLE
SCALE:20X



SOLDER MASK DETAILS

4221400/A 07/2014

NOTES: (continued)

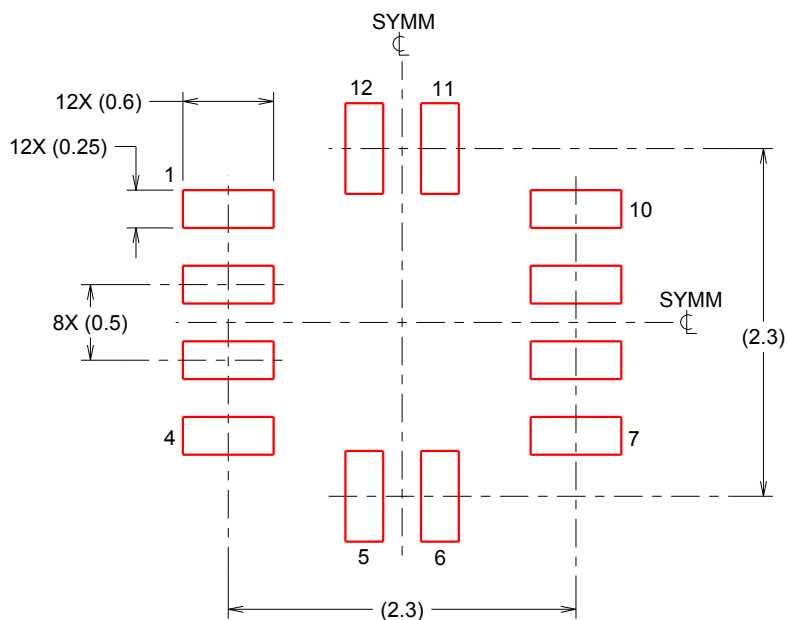
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

RMW0012A

VQFN - 1 mm max height

PLASTIC QUAD FLAT PACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:20X

4221400/A 07/2014

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

重要声明和免责声明

TI 提供技术和可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证没有瑕疵且不做任何明示或暗示的担保，包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任：(1) 针对您的应用选择合适的 TI 产品，(2) 设计、验证并测试您的应用，(3) 确保您的应用满足相应标准以及任何其他安全、安保或其他要求。这些资源如有变更，恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的应用。严禁对这些资源进行其他复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务，TI 对此概不负责。

TI 提供的产品受 TI 的销售条款 (<https://www.ti.com.cn/zh-cn/legal/termsofsale.html>) 或 [ti.com.cn](https://www.ti.com.cn) 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

邮寄地址：上海市浦东新区世纪大道 1568 号中建大厦 32 楼，邮政编码：200122
Copyright © 2021 德州仪器半导体技术（上海）有限公司